## NSN 5961-01-372-1072

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**Demilitarization:** 

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-372-1072 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.300 inches **Overall Height:** 0.039 inches **Overall Width:** 0.300 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Electrostatic sensitive and quality assurance level txv and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 70.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 900.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 95105-rc204-0079 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:**